

IRFB4137PBF

Request a Quote

IRFB4137PBF Information

www.electier.com	Part Number	IRFB4137PBF
	Manufacturer	Infineon Technologies
	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
	Description	MOSFET N-CH 300V 38A TO-220PAK
	Package	TO-220-3
		For the pricing/inventory/lead time, please contact
For Reference Only		us
		Website: https://www.heisener.com
		E-mail: salesdept@heisener.com

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IRFB4137PBF Specifications

Manufacturer Part Number	IRFB4137PBF
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	HEXFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	300V
Current - Continuous Drain (Id) @ 25°C	38A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10 V
Vgs(th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	125nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	5168pF @ 50V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	341W (Tc)
Rds On (Max) @ Id, Vgs	69 mOhm @ 24A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220
Package / Case	TO-220-3
	Report errors?

IRFB4137PBF Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE UARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IRFB4137PBF Payment Methods



IRFB4137PBF Shipping Methods



If you have any question about IRFB4137PBF, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com